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View Online at https://aerobasegroup.com/nsn/5961-00-016-4965 **Inclosure Material:** Metal **Overall Length:** 1.075 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.375 inches **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to base voltage, dc and 30.0 collector to emitter voltage, dc and 3.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 100.00 microamperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 35.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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